

## Applications

- Transient voltage protection
- High-voltage switches
- Crowbar
- Lasers
- Pulse generators



Application Note H - 6



**Remark:** For special selection of more than 2 pieces IXBOD 1-... for every break down voltage of  $V_{BO} > 2000$  V please contact us.

# Single Breakover Diode

$V_{BO} = 600-1000V$   
 $I_{AVM} = 0.9 A$

| $V_{BO}$<br>V | Standard<br>Types |
|---------------|-------------------|
| 600 ±50       | IXBOD 1 -06       |
| 700 ±50       | IXBOD 1 -07       |
| 800 ±50       | IXBOD 1 -08       |
| 900 ±50       | IXBOD 1 -09       |
| 1000 ±50      | IXBOD 1 -10       |



| Symbol        | Conditions  | Rated Values             |
|---------------|---|--------------------------|
| $I_D$         | $T_{VJ} = 125^\circ C; V = 0,8x V_{BO}$   | 20 $\mu A$               |
| $V_{BO}$      | $V_{BO}(T_{VJ}) = V_{BO, 25^\circ C} [1 + K_T (T_{VJ} - 25^\circ C)]$   |                          |
| $I_{RMS}$     | $f = 50 \text{ HZ}; T_{amb} = 50^\circ C$<br>connection pins soldered to printed circuit<br>(conductor 0,035x2mm) | 1.4 A                    |
| $I_{AVM}$     |   | 0.9 A                    |
| $I_{SM}$      | $t_p = 0.1 \text{ ms}; T_{amb} = 50^\circ C$ non repetitive   | 200 A                    |
| $I^2t$        | $t_p = 0.1 \text{ ms}; T_{amb} = 50^\circ C$  | 2 $A^2s$                 |
| $T_{amb}$     |   | -40...+125 $^\circ C$    |
| $T_{stg}$     |   | -40...+125 $^\circ C$    |
| $T_{VJm}$     |   | 125 $^\circ C$           |
| $K_T$         | Temperatur coefficient of $V_{BO}$  | $2 \cdot 10^{-3} K^{-1}$ |
| $K_p$         | coefficient for energy per pulse $E_p$ (material constant)  | 700 $K/Ws$               |
| $R_{thJA}$    | - natural convection<br>- with air speed 2 m/s  | 60 $K/W$<br>45 $K/W$     |
| <b>Weight</b> |   | 1 g                      |

| Symbol       | Conditions  | Characteristic Values |
|--------------|---|-----------------------|
| $I_{BO}$     | $T_{VJ} = 25^\circ C$   | 15 mA                 |
| $I_H$        | $T_{VJ} = 25^\circ C$   | 30 mA                 |
| $V_H$        | $T_{VJ} = 25^\circ C$   | 4 - 8 V               |
| $(dv/dt)_c$  | $T_{VJ} = 50^\circ C; V_D = 0.67 \cdot (V_{BO} + 100V)$   | > 1000 $V/\mu s$      |
| $(di/dt)_c$  | $T_{VJ} = 125^\circ C; V_D = V_{BO}; I_T = 80A; f = 50 \text{ Hz}$  | 200 $A/\mu s$         |
| $t_{q(typ)}$ | $T_{VJ} = 125^\circ C; V_D = 0.67 \cdot V_{BO}; V_R = 0V$<br>$dV/dt_{(lin.)} = 200V/\mu s; I_T = 80A; di/dt = -10A/\mu s$ | 150 $\mu s$           |
| $V_T$        | $T_{VJ} = 125^\circ C; I_T = 5A$  | 1.7 V                 |
| $V_{(TO)}$   | For power-loss calculations only  | 1.1 V                 |
| $r_T$        | $T_{VJ} = 125^\circ C$  | 0.12 $\Omega$         |

Dimensions in mm (1 mm = 0.0394")

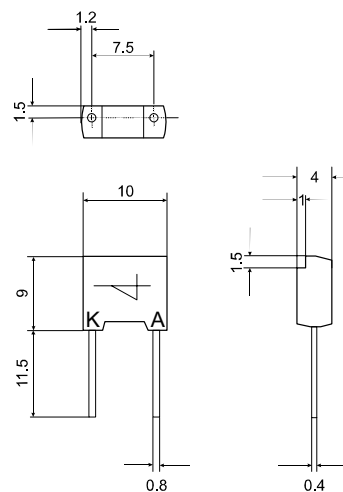




Fig. 1 Energy per pulse for trapezoidal current waveforms (see waveform definition).



Fig. 2 Energy per pulse for exponentially decaying current pulse (see waveform definition).



Fig. 3 On-state voltage



Fig. 4 Transient thermal resistance.

**Breakover Diode Modules**

Version: R

Version: RD

| $V_{BO}$<br>V | Standard<br>Types | BOD -<br>Elements | $V_{BO}$<br>V | Standard<br>Types | BOD -<br>Elements | $V_{BO}$<br>V | Standard<br>Types | BOD -<br>Elements |
|---------------|-------------------|-------------------|---------------|-------------------|-------------------|---------------|-------------------|-------------------|
| 1200 ±50      | IXBOD 1 -12R(D)   | 2                 | 2000 ±50      | IXBOD 1 -20R(D)   | 3                 | 3400 ±100     | IXBOD 1 -34R      | 4                 |
| 1300 ±50      | IXBOD 1 -13R(D)   | 2                 | 2100 ±50      | IXBOD 1 -21R(D)   | 3                 | 3600 ±100     | IXBOD 1 -36R      | 4                 |
| 1400 ±50      | IXBOD 1 -14R(D)   | 2                 | 2200 ±50      | IXBOD 1 -22R(D)   | 3                 | 3800 ±100     | IXBOD 1 -38R      | 4                 |
| 1500 ±50      | IXBOD 1 -15R(D)   | 2                 | 2300 ±50      | IXBOD 1 -23R(D)   | 3                 | 4000 ±100     | IXBOD 1 -40R      | 4                 |
| 1600 ±50      | IXBOD 1 -16R(D)   | 2                 | 2400 ±50      | IXBOD 1 -24R(D)   | 3                 | 4200 ±100     | IXBOD 1 -42R      | 4                 |
| 1700 ±50      | IXBOD 1 -17R(D)   | 2                 | 2500 ±50      | IXBOD 1 -25R(D)   | 3                 |               |                   |                   |
| 1800 ±50      | IXBOD 1 -18R(D)   | 2                 | 2600 ±100     | IXBOD 1 -26R(D)   | 3                 |               |                   |                   |
| 1900 ±50      | IXBOD 1 -19R(D)   | 2                 | 2800 ±100     | IXBOD 1 -28R(D)   | 3                 |               |                   |                   |
|               |                   |                   | 3000 ±100     | IXBOD 1 -30R(D)   | 3                 |               |                   |                   |
|               |                   |                   | 3200 ±100     | IXBOD 1 -32R(D)   | 3                 |               |                   |                   |

| Symbol     | Test Conditions   | 2 BODs            | 3 BODs            | 4 BODs            | 2-3 BODs<br>D-Version |   |
|------------|---|-------------------|-------------------|-------------------|-----------------------|---|
| $I_D$      | $T_{VJ} = 125^\circ\text{C}; V = 0,8x V_{BO}$   | 100               | 100               | 100               | 100                   | $\mu\text{A}$   |
| $V_{BO}$   |   |                   |                   |                   |                       | $V_{BO}(T_{VJ}) = V_{BO, 25^\circ\text{C}} [1 + K_T (T_{VJ} - 25^\circ\text{C})]$ |
| $I_{RMS}$  | $f = 50 \text{ Hz}; T_{amb} = 50^\circ\text{C}$<br>connection pins soldered to printed circuit<br>(conductor 0,035x2mm) | 2.0               | 1.4               | 1.1               | 0.3                   | A   |
| $I_{AVM}$  |   | 1.25              | 0.9               | 0.7               | 0.2                   | A   |
| $I_{SM}$   | $t_p = 0.1 \text{ ms}; T_{amb} = 50^\circ\text{C}$ non repetitive   | 200               | 200               | 200               | 50                    | A   |
| $I^2t$     | $t_p = 0.1 \text{ ms}; T_{amb} = 50^\circ\text{C}$  | 2                 | 2                 | 2                 | 0.125                 | $\text{A}^2\text{s}$  |
| $V_T$      | $T_{VJ} = 125^\circ\text{C}; I_T = 5\text{A}$   | 3.4               | 5.1               | 6.8               | 27                    | V   |
| $V_{(TO)}$ | For power-loss calculations only  | 2.2               | 3.3               | 4.4               | 17.5                  | V   |
| $r_T$      | $T_{VJ} = 125^\circ\text{C}$  | 0.24              | 0.36              | 0.48              | 3                     | $\Omega$  |
| $T_{amb}$  |   | -40...+125        | -40...+125        | -40...+125        | -40...+125            | $^\circ\text{C}$  |
| $T_{stg}$  |   | -40...+125        | -40...+125        | -40...+125        | -40...+125            | $^\circ\text{C}$  |
| $T_{VJm}$  |   | 125               | 125               | 125               | 125                   | $^\circ\text{C}$  |
| $K_T$      | Temperatur coefficient of $V_{BO}$  | $2 \cdot 10^{-3}$ | $2 \cdot 10^{-3}$ | $2 \cdot 10^{-3}$ | $2 \cdot 10^{-3}$     | $\text{K}^{-1}$   |
| $K_p$      | coefficient for energy per pulse $E_p$ (material constant)  | 700               | 700               | 700               | 700                   | $\text{K/Ws}$   |
| $R_{thJA}$ | - natural convection<br>- with air speed 2 m/s  | 20<br>16          | 20<br>16          | 20<br>16          | 20<br>16              | $\text{K/W}$<br>$\text{K/W}$  |
| Weight     | typical   | 14                | 14                | 14                | 14                    | g   |

| Symbol              | Test Conditions   | Characteristic Values <u>both</u> Versions R & RD | 2 BODs                               | 3 BODs                               | 4 BODs                               |  |
|---------------------|---|---|--------------------------------------|--------------------------------------|--------------------------------------|--|
| $I_{BO}$            | $T_{VJ} = 25^\circ\text{C}$   |   | 15                                   | 15                                   | 15                                   | $\text{mA}$  |
| $I_H$               | $T_{VJ} = 25^\circ\text{C}$   |   | 30                                   | 30                                   | 30                                   | $\text{mA}$  |
| $V_H$               | $T_{VJ} = 25^\circ\text{C}$   |   | 4 - 8                                | 4 - 8                                | 4 - 8                                | V  |
| $(dv/dt)_C$         | $T_{VJ} = 50^\circ\text{C}; V_D = 0.67 \cdot (V_{BO} + 100\text{V})$<br>- $V_{BO}$ bis 1500V<br>- $V_{BO}$ 1600 - 2000V<br>- $V_{BO}$ 2100 - 2500V<br>- $V_{BO}$ 2600 - 3000V<br>- $V_{BO}$ 3200 - 3400V<br>- $V_{BO}$ 3600 - 4200V |   | > 1000<br>> 1500<br>-<br>-<br>-<br>- | -<br>-<br>> 2000<br>> 2500<br>-<br>- | -<br>-<br>-<br>-<br>> 3000<br>> 3500 | $\text{V}/\mu\text{s}$<br>$\text{V}/\mu\text{s}$<br>$\text{V}/\mu\text{s}$<br>$\text{V}/\mu\text{s}$<br>$\text{V}/\mu\text{s}$<br>$\text{V}/\mu\text{s}$ |
| $(di/dt)_C$         | $T_{VJ} = 125^\circ\text{C}; V_D = V_{BO}; I_T = 80\text{A}; f = 50 \text{ Hz}$   |   | 200                                  | 200                                  | 200                                  | $\text{A}/\mu\text{s}$   |
| $t_{q(\text{typ})}$ | $T_{VJ} = 125^\circ\text{C}$<br>$dv/dt_{(\text{lin.})} = 200\text{V}/\mu\text{s}; I_T = 80\text{A}; di/dt = -10\text{A}/\mu\text{s}$  |   | 150                                  | 150                                  | 150                                  | $\mu\text{s}$  |



Dimensions in mm (1 mm = 0.0394")



Fig. 5 Energy per pulse for single BOD element for trapezoidal wave current.  $E_p$  must be multiplied by number of elements for total energy.



Fig. 6 Energy per pulse for single BOD element for exponentially decaying current pulse.  $E_p$  must be multiplied by number of elements for total energy.



Fig. 7 On-state voltage at  $T_{VJ} = 125^\circ\text{C}$ .



Fig. 8 Transient thermal resistance.

## Application

Protection of thyristors against overvoltages in forward direction.

$$V_{BO}(T_{VJ}) = V_{BO, 25^{\circ}C} [1 + KT(T_{VJ} - 25^{\circ}C)]$$



## Calculation example

a. The maximum junction temperature shall be calculated for a module IXBOD 1 -30R at an ambient temperature  $T_a = 60^{\circ}C$ , an exponentially decaying current  $I_{TM} = 40A$ , a pulsewidth  $t_p = 2 \mu s$ , an operating frequency  $f = 50 Hz$  and natural convection. From the diagram Fig. 6 the energy per pulse is obtained:

$$E_{p1} = 6 \times 10^{-3} \text{Ws}$$

For a module IXBOD1-30R the number of single IXBOD elements is:

$$n = 3$$

At natural air cooling the thermal resistance junction to ambient amounts to (Fig.8):

$$R_{thJA} = 20K/W$$

and the unknown temperature can be calculated as:

$$T_{VJmax1} = T_a + n \cdot f \cdot E_p \cdot R_{thJA} + K_p \cdot E_p$$

$$T_{VJmax1} = 60 + 18 + 4.2 = 82.2^{\circ}C$$

b. If following these steady-state conditions an overload for 1 minute occurs with  $I_{TM} = 60 A$  and a pulse-width  $t_p = 4 \mu s$  at the same operating frequency  $f = 50 Hz$ , then the resulting maximum junction temperature is calculating as follows:

$$T_{VJmax2} = T_{VJmax1} + (E_{p2} - E_{p1}) \cdot n \cdot f \cdot Z_{thJA}(t) + K_p \cdot (E_{p2} - E_{p1})$$

The diagrams Fig. 11 and Fig. 8 show

$$E_{p2} = 14 \times 10^{-3} \text{Ws}$$

$$Z_{thJA}(t = 1\text{min}) = 12K/W$$

From what follows:

$$T_{VJmax2} = 82.2 + 14.4 + 5.6 = 102.2^{\circ}C$$

which is allowed because the maximum admissible junction temperature  $T_{VJM} = 125^{\circ}C$ .

## Example of a circuit

A simple emergency triggering circuit.

- T : Thyristor
- $R_1$  : Current limiting resistance (0 - 200  $\Omega$ )
- $D_1$  : Series-diode (fast recovery diode)
- $D_3$  : Protection diode
- $D_4$  : Zener diode, typical  $V_Z$ : 3-6 V
- $R_2, C_2$  : Protection against parasitic triggering;  
recommended values:  
 $R_2$  : 100 - 1000  $\Omega$   
 $C_2$  : 22 - 47 nF
- $R_3, C_3$  : Snubber network of the thyristor



### Notice

1. A IXBOD element has a maximum reverse blocking voltage of 10V.
2. For higher reverse voltages a fast, soft recovery diode must be connected in series (Fig. 9). This diode must fulfill the conditions of Fig. 10.



Fig. 9 IXBOD protection by a fast recovery diode.



Fig. 10 Maximum peak value of the reverse current admissible for a given pulse-width  $t_B$ , which is required for the suitable fast recovery series-diode.





## Данный компонент на территории Российской Федерации

### Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

moschip.ru\_4

moschip.ru\_6

moschip.ru\_9